

Features

- · Trench LV MOSFET Technology
- · High Power and Current Handing Capability
- · Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

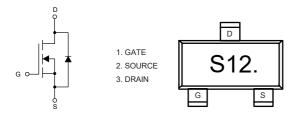
- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 100°C/W Junction to Ambient^(Note 2)

Parameter	Symbol	Rating	Unit		
Drain-Source Voltage	V _{DS}	20	V		
Gate-Source Volltage		V_{GS}	±8	V	
Continuous Drain Current	T _A =25°C	- I _D	5	А	
	T _A =70°C		4		
Pulsed Drain Current ^(Note 3)	I _{DM}	20	Α		
Total Power Dissipation (Note 4)		P _D	1.25	W	

Note:

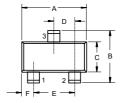
- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of $R_{\theta JA}$ is measured with the device mounted on $1in^2$ FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. P_D is based on max. junction temperature, using junction to ambient thermal resistance.

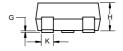
Internal Structure and Marking Code



N-Channel MOSFET

SOT-23

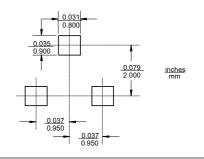






DIMENSIONS					
DIM	INCHES		MM		NOTE
DIIVI	MIN	MAX	MIN	MAX	NOTE
Α	0.110	0.120	2.80	3.04	
В	0.083	0.104	2.10	2.64	
С	0.047	0.055	1.20	1.40	
D	0.034	0.041	0.85	1.05	
E	0.067	0.083	1.70	2.10	
F	0.018	0.024	0.45	0.60	
G	0.0004	0.006	0.01	0.15	
Н	0.035	0.043	0.90	1.10	
J	0.003	0.007	0.08	0.18	
K	0.012	0.020	0.30	0.51	
L	0.007	0.020	0.20	0.50	

Suggested Solder Pad Layout





Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit	
Static Characteristics							
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	20			V	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_D=250\mu A$	0.45	0.7	1.0	V	
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±8V, V _{DS} =0V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V			1	μA	
Drain-Source On-Resistance		V _{GS} =4.5V, I _D =5A		14	31.8	6 mΩ	
	R _{DS(on)}	V _{GS} =2.5V, I _D =4.7A		18	35.6		
		V _{GS} =1.8V, I _D =4.3A		24	41.4		
Forward Transconductance	g _{FS}	V _{DS} =10V, I _D =4A		30		S	
Gate Resistance	R _g	f=1 MHz, Open drain		3		Ω	
Diode Characteristics							
Continuous Body Diode Current	Is				5	Α	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =4A			1.2	V	
Reverse Recovery Time	t _{rr}	1 -2 4A dl /dt-200A/up		10		ns	
Reverse Recovery Charge	Q _{rr}	I _F =3.4A, dI _F /dt=200A/μs		6		nC	
Dynamic Characteristics	-						
Input Capacitance	C _{iss}			668			
Output Capacitance	C _{oss}	V_{DS} =10V, V_{GS} =0V,f=1MHz		114		pF	
Reverse Transfer Capacitance	C _{rss}			102			
Total Gate Charge	Q _g			11			
Gate-Source Charge	Q_{gs}	V_{DS} =10V, V_{GS} =4.5V, I_{D} =3A		1.8		nC	
Gate-Drain Charge	Q_{gd}			3			
Turn-On Delay Time	t _{d(on)}			6.4			
Turn-On Rise Time	t _r	V _{DD} =10V,V _{GS} =10V,		12.6			
Turn-Off Delay Time	t _{d(off)}	$R_G=2.2\Omega$, $I_D=1A$		21		ns -	
Turn-Off Fall Time	t _f			2.6			



Curve Characteristics

Fig.1 - Typical Output Characteristics

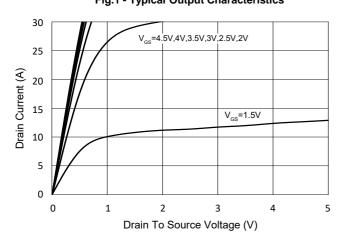


Fig.2 - Transfer Characteristic

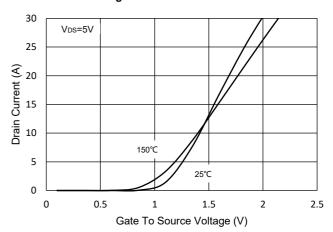


Fig.3 - R_{DS(ON)} - V_{GS}

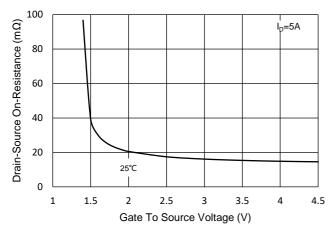


Fig.4 - $R_{DS(ON)}$ - I_D

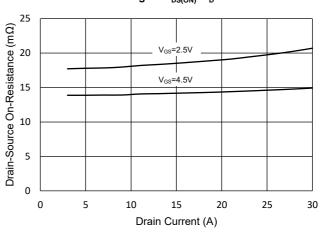


Fig.5 - Capacitance Characteristics

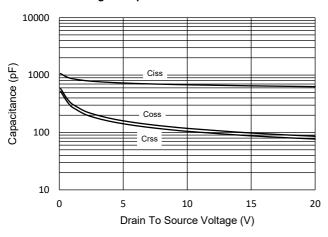
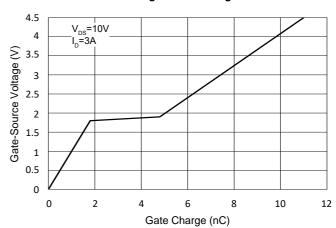
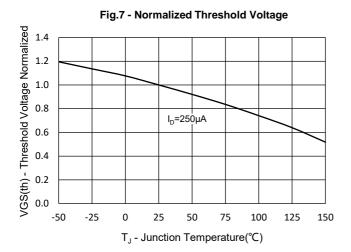


Fig.6 - Gate Charge





Curve Characteristics



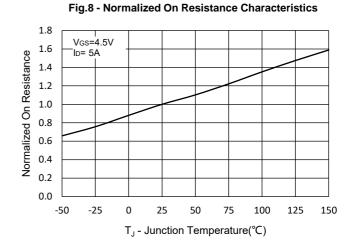
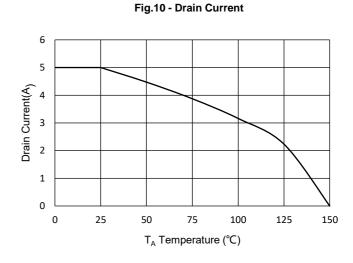
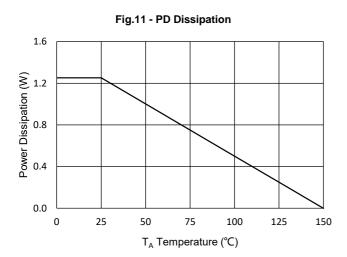


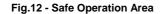
Fig.9 - I_S - V_{SD} 100 V_{GS}=0V Source Current (A) 10 150℃ 25℃ 1 0.1 0.0 0.2 0.4 0.6 0.8 1.0 1.2 Source To Drain Voltage (V)







Curve Characteristics



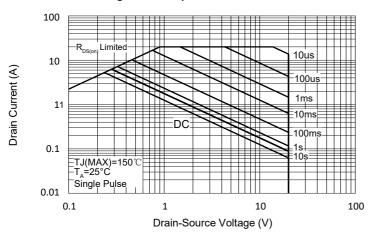
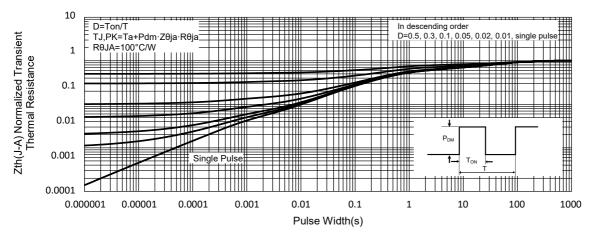


Fig.13 - Normalized Transient Thermal Impedance





Ordering Information

Device	Packing
Part Number-TP	Tape&Reel:3Kpcs/Reel

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